

# Optical and photoelectrical properties of Ce<sup>3+</sup> and Mg<sup>2+</sup>-Si<sup>4+</sup> co-doped Gd<sub>3</sub>Ga<sub>5</sub>O<sub>12</sub> and Gd<sub>3</sub>Ga<sub>3</sub>Al<sub>2</sub>O<sub>12</sub> single crystalline films

Tetiana Zorenko<sup>1#</sup>, Vitalii Gorbenko, Sandra Witkiewicz-Łukaszek<sup>1</sup>,  
Artur Majewski-Napierkowski<sup>1</sup>, Mikołaj Kaminski<sup>2</sup>, Sebastian Mahlik<sup>2</sup>,  
Tadeusz Leśniewski<sup>2</sup>, Yuriy Zorenko<sup>1</sup>

<sup>1</sup>Faculty of Physics of Kazimierz Wielki University in Bydgoszcz, 85-090 Bydgoszcz, Poland

<sup>2</sup>Institute of Experimental Physics of Faculty of Mathematics, Physics and Informatics,  
University of Gdansk, 80-308 Gdansk, Poland

In this work, we present the results of crystallization and investigation of the optical and photoelectrical properties singly Ce<sup>3+</sup>, doubly Ce<sup>3+</sup>-Mg<sup>2+</sup>, and triply Ce<sup>3+</sup>-Mg<sup>2+</sup>-Si<sup>4+</sup> doped of Gd<sub>3</sub>Ga<sub>5</sub>O<sub>12</sub> and Gd<sub>3</sub>Ga<sub>3</sub>Al<sub>2</sub>O<sub>12</sub> single crystalline films (SCF). These garnets possess a relatively low band gap  $E_g = 6.2-6.4$  eV compared to well-known YAG and LuAG garnets with  $E_g = 7.8-8$  eV and can be suitable for the creation of photo-sensitive e/h trapping levels in the case of Mg<sup>2+</sup>-Si<sup>4+</sup> donor-acceptor doping.

The SCF samples were grown by the liquid phase epitaxy (LPE) method onto Gd<sub>3</sub>Ga<sub>5</sub>O<sub>12</sub> (GGG) and Gd<sub>3</sub>Ga<sub>2.5</sub>Al<sub>2.5</sub>O<sub>12</sub> (GAGG) substrates, respectively, from the melt-solution based on the PbO-B<sub>2</sub>O<sub>3</sub> flux. The absorption, luminescence, and photoelectrical properties of Ce<sup>3+</sup> doped and Mg<sup>2+</sup>-Si<sup>4+</sup> codoped SCFs of GGG and GAGG garnets were investigated using conventional spectral methods and compared with the properties of the reference GGG:Ce and GAGG:Ce crystal and ceramic samples. In addition, the influence of the thermal annealing at 1300 °C in air and in 95% N<sub>2</sub> - 5% H<sub>2</sub> reducing atmosphere on the optical and photoelectrical properties of both types of SCFs was investigated.

Moreover, the luminescent properties of selected SCF samples were studied at 10 K under excitation by synchrotron radiation (SR) with energy in the 3.5-12.0 eV range at P66 Superlumi station at PETRA 3 storage ring at DESY, Germany. Based on these results, the energy structure of different Ce<sup>3+</sup> related centers in Mg<sup>2+</sup>-Si<sup>4+</sup> codoped SCF samples were compared with respect to the band structure of these garnets.

The results of this complex study are helpful for the development of luminescent materials for composite photovoltaic screens as well as for the creation of the composite thermoluminescent and optically-stimulated detectors based on the epitaxial structures of Ce<sup>3+</sup> doped and Mg<sup>2+</sup>-Si<sup>4+</sup> codoped garnets, producing by LPE growth method.

**Acknowledgements:** The work was performed in the frame of NCN Poland no 2019/33/B/ST3/00406 project and partly in the frame of MNSW Poland Regional Excellence Initiative nr RID/SP/0048/2024/01 project. An investigation with SR at Superlumi station at DESY was performed in the frame of I-20210147 EC, I-20220044, and I-20220864 projects.

# corresponding author: tzorenko@ukw.edu.pl